TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

74HC595D

8-Bit Shift Register/Latch (3-state)

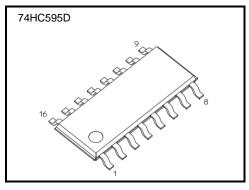
The 74HC595D is a high speed 8-BIT SHIFT REGISTER/LATCH fabricated with silicon gate C^2MOS technology.

It achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The 74HC595D contains an 8-bit static shift register which feeds an 8-bit storage register.

Shift operation is accomplished on the positive going transition of the SCK input. The output register is loaded with the contents of the shift register on the positive going transition of the RCK input. Since RCK and SCK signal are independent, parallel outputs can be held stable during the shift operation.

And, since the parallel outputs are 3-state, it can be directly connected to 8-bit bus. This register can be used in serial-to-parallel conversion, data receivers, etc.



Weight

P-SOP16-0410-1.27-005 : 0.15 g (typ.)

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $f_{max} = 55 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Output drive capability: 15 LSTTL loads for QA to QH 10 LSTTL loads for QH'
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 6 \text{ mA (min)}$

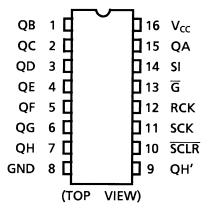
For QA to QH

 $|I_{OH}| = I_{OL} = 4 \text{ mA (min)}$

For QH'

- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 6 V

Pin Assignment

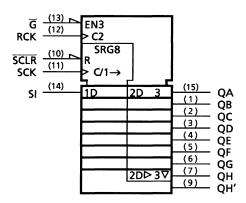




Marking

TBD

IEC Logic Symbol



Truth Table

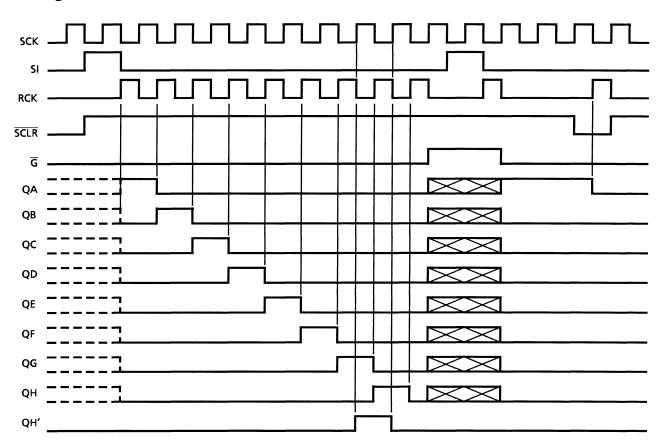
		Inputs			
SI	SCK	K SCLR RCK G			Function
Х	Х	Х	Х	Н	QA thru QH outputs disable
Х	Х	Х	Х	L	QA thru QH outputs enable
Х	Х	L	Х	Х	Shift register is cleared.
L		Н	Х	Х	First stage of S.R. becomes "L". Other stages store the data of previous stage, respectively.
Н		Н	Х	Х	First stage of S.R. becomes "H". Other stages store the data of previous stage, respectively.
Х	\neg	Н	Х	Х	State of S.R. is not changed.
Х	Х	Х		Х	S.R. data is stored into storage register.
Х	Х	Х	1	Х	Storage register stage is not changed.

2

X: Don't care

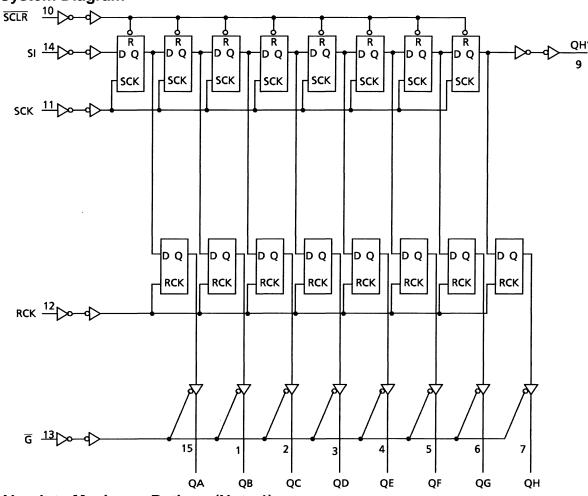


Timing Chart



3

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	–0.5 to 7	V
DC input voltage	VIN	−0.5 to V _{CC} + 0.5	٧
DC output voltage	Vout	−0.5 to V _{CC} + 0.5	٧
Input diode current	lıK	±20	mA
Output diode current	lok	±20	mA
DC output current (QH')	lour	±25	mΛ
(QA to QH)	Іоит	±35	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

4

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	Vcc	2 to 6	V
Input voltage	VIN	0 to Vcc	٧
Output voltage	Vout	0 to V _{CC}	٧
Operating temperature	T _{opr}	-40 to 125	°C
		0 to 1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns
		0 to 400 (V _{CC} = 6.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition				Ta = 25°C			Ta = -40 to 85°C		Ta = -40 to 125°C		Unit
• naraotono no	C y				V _{CC} (V)	Min	Тур.	Max	Min	Max	Min	Max	
					2.0	1.50	_	_	1.50	_	1.50	_	
High-level input voltage	VIH			_	4.5	3.15	_	_	3.15	_	3.15	_	V
					6.0	4.20		_	4.20	_	4.20	_	
					2.0	_		0.50	_	0.50	_	0.50	
Low-level input voltage	VIL			_	4.5	_	_	1.35	_	1.35	_	1.35	V
Ū					6.0	_	_	1.80	_	1.80	_	1.80	
		l.,			2.0	1.9	2.0	_	1.9	_	1.9	_	
	Vон	VIN = VIH	or VIL	$I_{OH} = -20~\mu A$	4.5	4.4	4.5	_	4.4	_	4.4	_	V
			J. VIL		6.0	5.9	6.0	_	5.9	_	5.9	_	
High-level output voltage			QH'	IOH = -4 mA	4.5	4.18	4.31	_	4.13	_	3.7	_	V
			QII	IOH = -5.2 mA	6.0	5.68	5.80	_	5.63	_	5.2	_	
			QA to QH	IOH = -6 mA	4.5	4.18	4.31	_	4.13	_	3.7	_	
				$I_{OH} = -7.8 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	5.2	_	
	Vol			I _{OL} = 20 μA	2.0	_	0.0	0.1	_	0.1	_	0.1	
		VIN = VIH	IH or VIL		4.5	_	0.0	0.1	_	0.1	_	0.1	V
					6.0	_	0.0	0.1	_	0.1	_	0.1	
Low-level output voltage			QH'	IOL = 4 mA	4.5	_	0.17	0.26	_	0.33	_	0.4	
			QII	IOL = 5.2 mA	6.0	_	0.18	0.26	-	0.33		0.4	V
			QA to	IOL = 6 mA	4.5	_	0.17	0.26	_	0.33	_	0.4	V
			QH	IOL = 7.8 mA	6.0	_	0.18	0.26	-	0.33		0.4	
3-state output off-state current	loz	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		6.0	_	_	±0.5	_	±5.0		±10.0	μА	
Input leakage current	lın	V _{IN} = V _{CC} or GND			6.0	_	_	±0.1	_	±1.0	_	±1.0	μА
Quiescent supply current	Icc	V _{IN} =	V _{CC} or	GND	6.0	_		4.0	_	40.0		160.0	μА



Timing Requirements (input: tr = tf = 6 ns)

Characteristics	Symbol		Ta = 25°C		Ta = -40 to 85°C	Ta = -40 to 125°C	Unit	
			V _{CC} (V)	Тур.	Limit	Limit	Limit	
Minimum pulse width	ta (())		2.0	_	75	95	110	
(SCK, RCK)	tw (H)	_	4.5	_	15	19	22	ns
(SOK, KOK)	tvv (L)		6.0		13	16	19	
Minimum pulse width			2.0		75	95	110	
(SCLR)	tw (L)	_	4.5	_	15	19	22	ns
(SCLK)	tw (L)		6.0		13	16	19	
Minimum set-up time			2.0	_	50	65	75	
(SI-SCK)	ts	_	4.5	_	10	13	15	ns
(31-3011)			6.0	_	9	11	13	
Minimum set-up time			2.0	_	75	95	110	
(SCK-RCK)	ts	_	4.5	_	15	19	22	ns
(OOK NOIL)			6.0	_	13	16	19	
Minimum set-up time			2.0	_	100	125	150	
(SCLR -RCK)	ts	_	4.5	_	20	25	30	ns
(SOLIC-NOIC)			6.0		17	21	26	
			2.0	_	0	0	0	
Minimum hold time	th	_	4.5	_	0	0	0	ns
			6.0		0	0	0	
Minimum removal time			2.0		50	65	75	
(SCLR)	t _{rem}	_	4.5	_	10	13	15	ns
			6.0		9	11	13	
			2.0	_	6	5	4	
Clock frequency	f	_	4.5	_	30	25	20	MHz
			6.0	_	35	28	24	

AC Characteristics (CL = 15 pF, VCC = 5 V, Ta = 25°C, input: tr = tf = 6 ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time (QH')	t _{TLH}	_	_	4	8	ns
Propagation delay time (SCK-QH')	t _{pLH}	_	_	12	21	ns
Propagation delay time (SCLR -QH')	^t pHL	_	_	15	30	ns
Maximum clock frequency	f _{max}	_	35	77	_	MHz



AC Characteristics (input: tr = tf = 6 ns)

		Test Condition			Ta = 25°C			Ta = -40 to 85°C		Ta = -40 to 125°C			
Characteristics	Symbol		CL (pF)	Vcc (V)	Min	Тур.	Max	Min	Max	Min	Max	Unit	
Output transition time (Q _n)	tTLH tTHL	_	50	2.0 4.5 6.0	_ _ _	25 7 6	60 12 10	 - -	75 15 13	_ _ _	90 18 15	ns	
Output transition time (QH')	tTLH tTHL	_	50	2.0 4.5 6.0		30 8 7	75 15 13		95 19 16	_ _ _	115 23 20	ns	
Propagation delay time (SCK-QH')	t _{pLH}	_	50	2.0 4.5 6.0	_ _ _	45 15 13	125 25 21		155 31 26	_ _ _	240 48 31	ns	
Propagation delay time (SCLR -QH')	tрНL	_	50	2.0 4.5 6.0	— — —	60 18 15	175 35 30	 - -	220 44 37	_ _ _	265 53 45	ns	
Propagation delay time	^t pLH	_	50	2.0 4.5 6.0	_ _ _	60 20 17	150 30 26	_ _ _	190 38 32	_ _ _	265 53 45	ns	
(RCK-Q _n)	tpHL		150	2.0 4.5 6.0		75 25 22	190 38 32		240 48 41		285 57 48		
Output enable time	tpZL tpZH	R _L = 1 kΩ	50	2.0 4.5 6.0	_ _ _	45 15 13	135 27 23		170 34 29	_ _ _	225 45 38	ns	
output shaste time		tpZH	tpZH	1,2	150	2.0 4.5 6.0	_ _ _	60 20 17	175 35 30		220 44 37	_ _ _	265 53 45
Output disable time	tpLZ tpHZ	$R_L = 1 \text{ k}\Omega$	50	2.0 4.5 6.0	_ _ _	30 15 14	150 30 26	_ _ _	190 38 33	_ _ _	225 45 38	ns	
Maximum clock frequency	f _{max}	_	50	2.0 4.5 6.0	6 30 35	17 50 59	_ _ _	5 25 28	_ _ _	4 20 24	_ _ _	MHz	
Input capacitance	C _{IN}	_	_		_	3	_		_	_	_	pF	
Power dissipation capacitance	C _{PD} (Note)		-		_	41	_	_	_	_	_	pF	

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

7

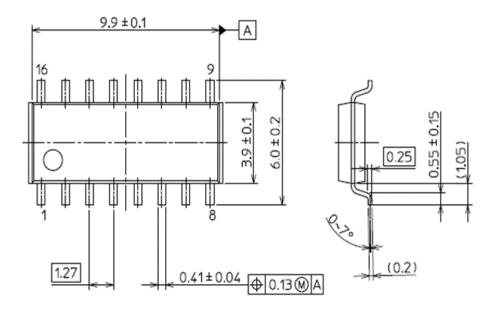
Average operating current can be obtained by the equation:

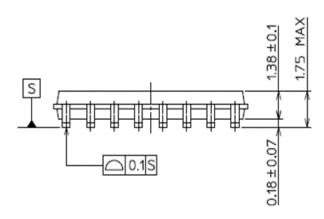
ICC (opr) = CPD·VCC·fIN + ICC

Package Dimensions

P-SOP16-0410-1.27-005

Unit:mm





Weight: 0.15 g (typ.)

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